

Peak gate current ($t_p=20\mu s$, $T_j=150$)	I_{GM}	4	A
Average gate power dissipation ($T_j=150$)	$P_{G(AV)}$	1	W
Peak gate power	P_{GM}	10	W
Peak pulse voltage ($T_j=25$; non-repetitive,off-state;FIG.7)	V_{pp}	0.5	kV

ELECTRICAL CHARACTERISTICS ($T_j=25$ unless otherwise specified)

Symbol	Test Condition	Value		Unit
		MIN.(T	(	

ORDERING INFORMATION

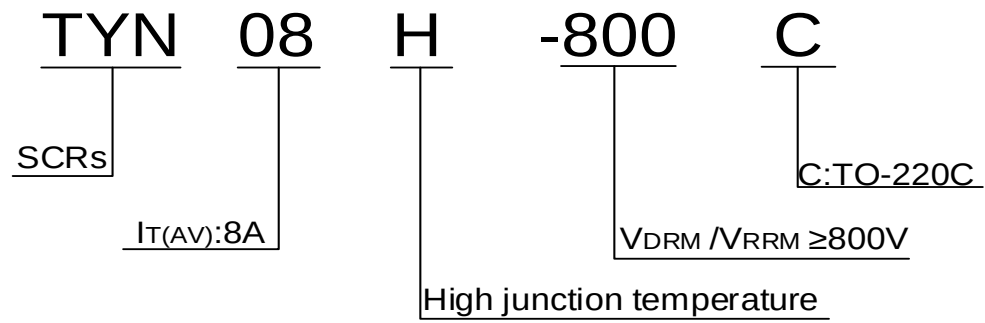
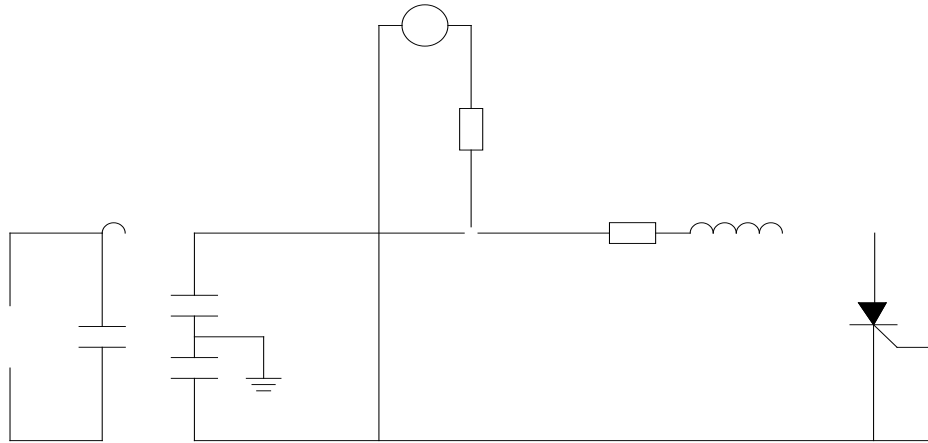


FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards.



TYN08H-800C

JieJie M

